

## SCHOTTKY BARRIER DIODE

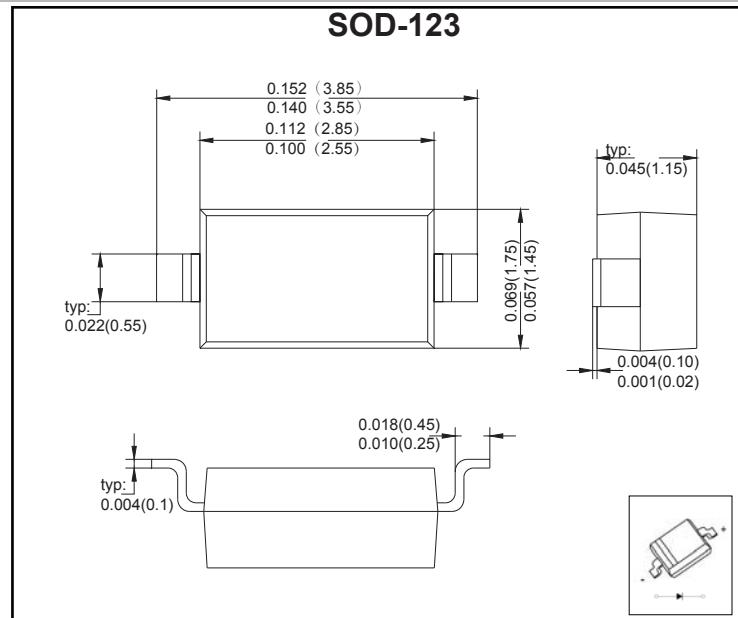
VOLTAGE RANGE: 40V PEAK PULSE POWER:500mW

## FEATURES

- Low Forward Voltage Drop
- Guard Ring Construction for Transient
- Protection High Conductance
- Also Available in Lead Free Version

## MECHANICAL DATA

- Case: SOD-123 Small Outline Plastic Package
- Polarity: Color band denotes cathode end
- Mounting Position: Any



## MAXIMUM RATINGS AND CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified

Parameter	Symbol	Value	Unit
Peak repetitive peak reverse voltage	$V_{RRM}$		
Working peak reverse voltage	$V_{RWM}$	40	V
DC blocking voltage	$V_R$		
RMS reverse voltage reverse voltage (DC)	$V_{R(RMS)}$	28	V
Average rectified output current	$I_o$	0.5	A
Non-repetitive Peak Forward Surge Current @t=8.3ms	$I_{FSM}$	5.5	A
Power dissipation	$P_D$	500	mW
Thermal resistance junction to ambient	$R_{\theta JA}$	200	°C/W
Junction temperature	$T_j$	125	°C
Storage temperature	$T_{STG}$	-55~+150	°C
Voltage rate of change	$dv/dt$	1000	V/μs

## Electrical Specification (TA=25@25°C unless otherwise specified)

	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse breakdown voltage	$V(BR)$	$R_I = 20\mu A$	40			V
Reverse current	$I_R$ $R=V$	=20V			10	uA
		40V			20	
Forward voltage	$V_F$	$I_F=0.5A$			0.51	V
		$I_F=1.0A$			0.62	
Capacitance between terminals	$C_T$	$V_R=0, f=1MHz$			170	pF

MARKING:SF

## RATINGS AND CHARACTERISTIC CURVES

